

Programmable Digital-Unipolar Hall Effect Sensor

FEATURES

- Programmable Unipolar Hall sensor
- High chopping frequency
- Supports a wide voltage range
 - 2.5 to 24V
 - Operation from unregulated supply
- Wide operating temperature range
- Factory-programmed at end-of-line for optimum
- Reverse battery protection (up to 28V)
- Over-voltage protection at all pins
- Robust EMC performance
- Solid-state reliability
- Small package
 - 3-pin SIP -(UA)
 - 3-pin SOT23 -(SO)

APPLICATIONS

- Flow meters
- Valve and solenoid status
- BLDC motors with sensors
- Proximity sensing
- Tachometers

DESCRIPTION

The SC243X family, produced with Bi-CMOS technology, is a chopper-stabilized Hall Effect Sensor that offers a magnetic sensing solution with superior sensitivity stability over temperature and integrated protection features.

Superior high-temperature performance is made possible through dynamic offset cancellation, which reduces the residual offset voltage normally caused by device over molding, temperature dependencies, and thermal stress. Each device includes on a single silicon chip a voltage regulator, Hall-voltage generator, small-signal amplifier, chopper stabilization, Schmitt trigger, and an open-drain output to sink up to 20mA.

An onboard regulator permits with supply voltages of 2.5 to 24V which makes the device suitable for a wide range of industrial and automotive applications

The device is available in a 3-pin SIP package (UA) and a 3-pin SOT-23 style package (SO). Both are lead (Pb) free, with 100% matte tin lead frame plating.



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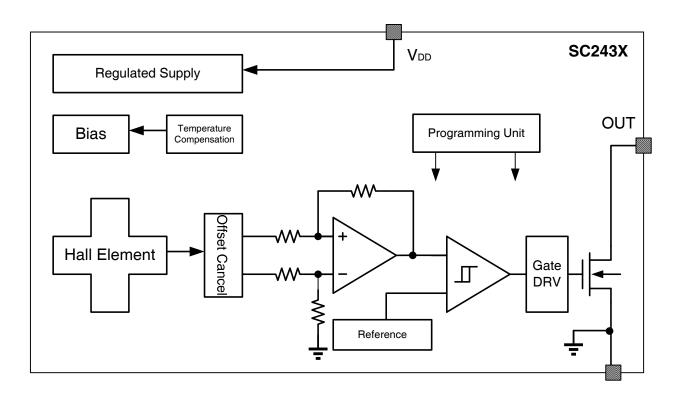
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BLOCK DIAGRAM



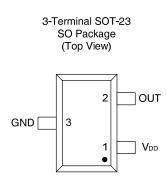


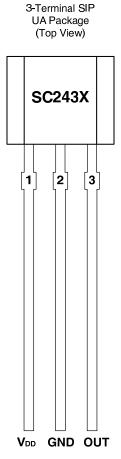
ORDERING INFORMATION

Part Number	Packing	Mounting	Ambient, T _A	B _{OP} (Typ.)	B _{RP} (Typ.)
SC2432UA	Bulk, 1000 pieces/bag	3-pin SIP		+2.5mT	+2.0mT
SC2434SO	Reel, 3000pieces/reel	SOT23	-40℃ ~ 150℃	+2.5mT	+2.0mT
SC2434SO-N	Reel, 3000pieces/reel	SOT23		-2.5mT	-2.0mT
SC2434UA	Bulk, 1000 pieces/bag	3-pin SIP		+7.0mT	+5.5mT
SC2434SO	Reel, 3000pieces/reel	SOT23	-40℃ ~ 150℃	+7.0mT	+5.5mT
SC2434SO-N	Reel, 3000pieces/reel	SOT23		-7.0mT	-5.5mT
SC2438UA	Bulk, 1000 pieces/bag	3-pin SIP	40°C 450°C	+12.0mT	+9.5mT
SC2438SO	Reel, 3000pieces/reel	SOT23	-40℃ ~ 150℃	+12.0mT	+9.5mT



TERMINAL CONFIGURATION





Ter	Terminal Number			
Nama			Type	Description
Name	UA	SO		
V_{DD}	1	1	PWR	2.5V~24 V power supply
GND	2	3	Ground	Ground terminal
OUT	3	2	Output	Open-drain output. The open drain requires a pull-up resistor

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ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted) (1)

Parameter	Symbol	Min.	Max.	Units
Power supply voltage	V_{DD}	-28 ⁽²⁾	28	V
Output terminal voltage	Vout	-0.5	28	V
Output terminal current sink	Isink	0	30	mA
Operating ambient temperature	T _A	-40	150	$^{\circ}$
Maximum junction temperature	TJ	-55	165	$^{\circ}$
Storage temperature	T _{STG}	-65	175	$^{\circ}$

⁽¹⁾ Stresses above those listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ESD PROTECTION

Human Body Model (HBM) tests according to: standard AEC-Q100-002 HBM

Parameter	Symbol	Min.	Max.	Units
ESD-Protection	V _{ESD}	-4	4	kV

THERMAL CHARACTERISTICS

Symbol	Parameter	Test Conditions	Rating	Units
R _# JA	UA Package thermal resistance	Single-layer PCB, with copper limited to solder pads	166	°C/W
$R_{{\scriptscriptstyle heta} JA}$	SO Package thermal resistance	Single-layer PCB, with copper limited to solder pads	228	°C/W

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⁽²⁾ Ensured by design.



OPERATING CHARACTERISTICS

Electrical Characteristics

over operating free-air temperature range ($V_{DD} = 5.0V$, unless otherwise noted)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
V_{DD}	Operating voltage (1)	$T_J < T_{J(Max.)}$	2.5		24	V
V_{DDR}	Reverse supply voltage		-28			V
I _{DD} (off)	Operating aupply aurrent	V _{DD} =2.5 to 24 V, T _A =25℃		1.6	2.5	mA
I _{DD} (on)	Operating supply current	V _{DD} =2.5 to 24 V, T _A =25℃		1.6	2.5	mA
t _{on}	Power-on time			35	50	μS
IQL	Off-state leakage current	Output Hi-Z			1	μΑ
Б		V_{DD} =5.0V, I_{O} =10mA, T_{A} =25 $^{\circ}$ C		20		Ω
R _{DS(on)} FET on-resistance	FET on-resistance	V_{DD} =5.0V, I_{O} =10mA, T_{A} =125 $^{\circ}$ C		30		Ω
t d	Output delay time	B=B _{RP} to B _{OP}		15	25	μS
tr	Output rise time (10% to 90%)	R1=1Kohm Co=50pF			0.5	μS
t _f	Output fall time (90% to 10%)	R1=1Kohm Co=50pF			0.2	μS

Maximum voltage must be adjusted for power dissipation and junction temperature, see Thermal Characteristics

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Magnetic Characteristics

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
f _{BW}	BW		20			kHz
SC2432	+2.5 /+2.0 mT					
Вор	Operating point		1.5	2.5	3.5	mT
B _{RP}	Release point	T _A =25°C	1.0	2.0	3.0	mT
Внуѕ	Hysteresis			0.5		mT
SC2434	SC2434 +7.0 /+5.5 mT					
Вор	Operating point		6.0	7.0	8.0	mT
B _{RP}	Release point	T _A =25°C	4.5	5.5	6.5	mT
Внуѕ	Hysteresis			1.5		mT
SC2438	SC2438 +12.0 /+9.5 mT					
Вор	Operating point		10.0	12.0	14.0	mT
B _{RP}	Release point	T _A =25°C	7.5	9.5	11.5	mT
Внуѕ	Hysteresis			2.5		mT

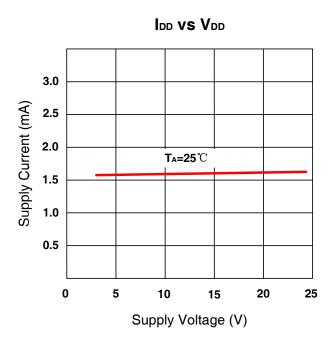
1mT=10Gs

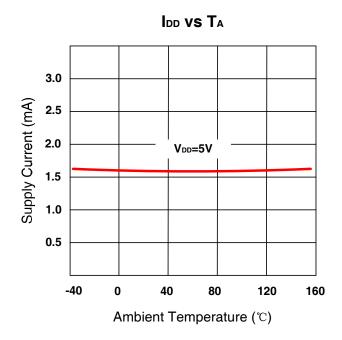
Magnetic flux density, B, is indicated as a negative value for North-polarity magnetic fields, and as a positive value for South-polarity magnetic fields.

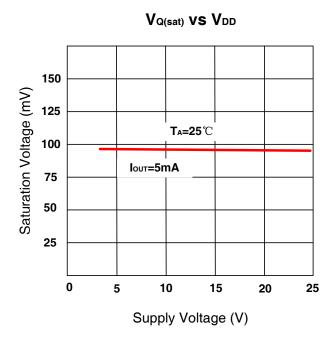
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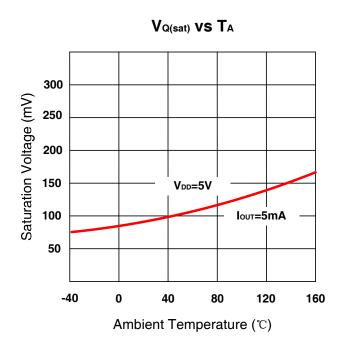


TYPICAL CHARACTERISTICS









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FUNCTION DESCRIPTION OVERVIEW

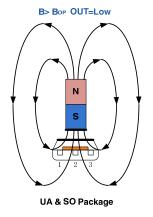
The SC243X device is a chopper-stabilized Hall sensor with a digital latched output for magnetic sensing applications. The device can be powered with a supply voltage between 2.5 and 24V, and continuously survives continuous -28V reverse-battery conditions. The device does not operate when -28 to 2.2V is applied to the VDD terminal (with respect to the GND terminal). In addition, the device can withstand voltages up to 40V for transient durations.

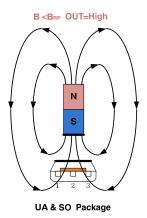
The output of SC243X switches low (turns on) when a magnetic field (South polarity) perpendicular to the Hall element exceeds the operate point threshold, Bop. After turn-on, the output is capable of sinking 20mA and the output voltage is VQ (sat). When the magnetic field is reduced below the release point, BRP, the device output goes high (turns off). The difference in the magnetic operate and release points is the hysteresis, BHYS, of the device. This built-in hysteresis allows clean switching of the output even in the presence of external mechanical vibration and electrical noise.

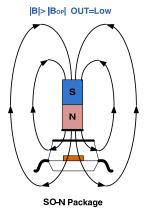
An external output pull-up resistor is required on the OUT terminal. The OUT terminal can be pulled up to V_{DD} or to a different voltage supply. This allows for easier interfacing with controller circuits.

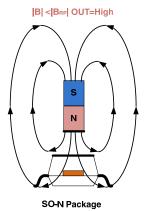
Field Direction Definition

A positive magnetic field is defined as a South pole near the marked side of the package.









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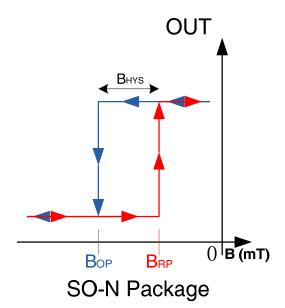
Transfer Function

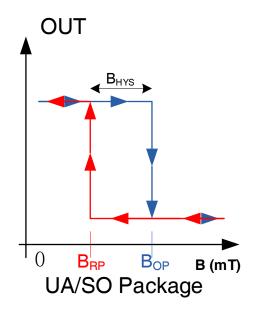
Powering-on the device in the hysteresis region, less than B_{OP} and higher than B_{RP} , allows an indeterminate output state. The correct state is attained after the first excursion beyond B_{OP} or B_{RP} . If the field strength is greater than B_{OP} , then the output is pulled low. If the field strength is less than B_{RP} , the output is released.

Bop—magnetic threshold for activation of the device output, turning in ON (low) state

B_{RP}—magnetic threshold for release of the device output, turning in OFF (high) state.

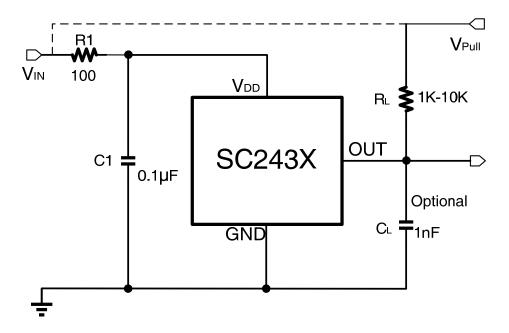
BHYS= BOP - BRP







TYPICAL APPLICATION



The SC243X contains an on-chip voltage regulator and can operate over a wide supply voltage range. In applications that operate the device from an unregulated power supply, transient protection must be added externally. For applications using a regulated line, EMI/RFI protection may still be required. It is recommended to shunt C1 capacitors to the ground near the chip V_{DD} power supply, with a typical value of 0. 1µF.At the same time in the external optional series resistor R1 their typical values for 100 Ω . The output capacitor C_L is used as the output filter, typically 1nF.

Select a value for C_L based on the system bandwidth specifications as:

$$C_L = \frac{1}{2\pi \times R \times f(Hz)}$$

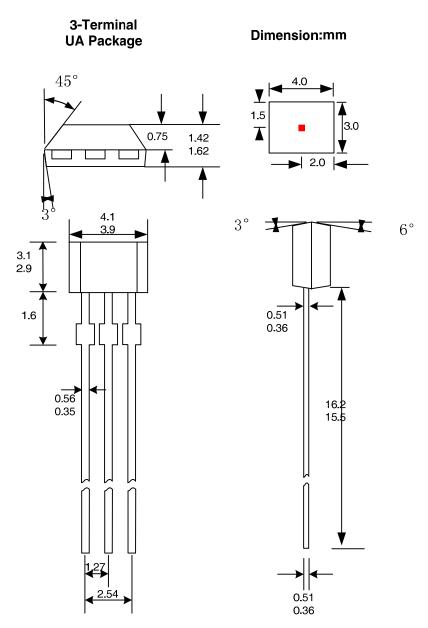
The output stage of the SC243X device is a drain open-circuit NMOS tube, which provides a load capacity of 20mA. Adjust the pull-up resistor R_L to make it work properly. The R_L provides a high level for the leak-opening output. In general, less current is better, but faster transient response and bandwidth are required, with a smaller resistor R_L for faster switching.

 V_{PULL} is not restricted to V_{DD} , and could be connected to other voltage reference. The allowable voltage range of this terminal is specified in the Absolute Maximum Ratings.

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PACKAGE INFORMATION "UA"



Notes:

- 1. Exact body and lead configuration at vendor's option within limits shown.
- 2. Height does not include mold gate flash.

Where no tolerance is specified, dimension is nominal.

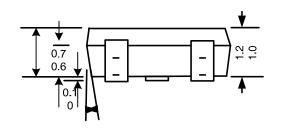
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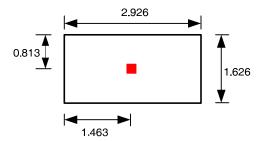


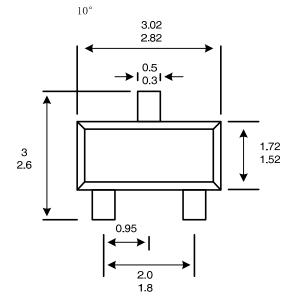
PACKAGE INFORMATION "SO"

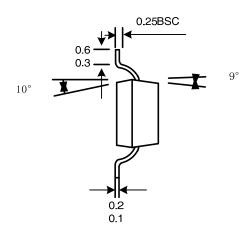
3-Terminal SO Package

Dimension:mm









Notes:

- 1. Exact body and lead configuration at vendor's option within limits shown.
- 2. Height does not include mold gate flash.

Where no tolerance is specified, dimension is nominal.

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REVISON HISTORY

Revision	Date	Description
Rev1.0	2016-05-10	Preliminary datasheet
Rev1.1	2017-08-06	Add order information of SC2438SO
Rev2.3	2019-05-06	The final revision of old datasheet
RevA/1.0	2021-01-04	Unified datasheet format
RevA/1.1	2024-05-06	Update part number in order information
RevA/1.2	2024-07-19	Correct SC2438 magnetic parameter

单击下面可查看定价,库存,交付和生命周期等信息

>>Semiment (赛卓电子)